NSN 5961-00-320-7584

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-320-7584 **Inclosure Material:** Metal **Overall Length:** 0.375 inches **Overall Diameter:** 0.875 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 30.0 breakdown voltage, collector-to-base, emitter open and 30.0 breakdown voltage, collector-to-emitter, base open and 4.8 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** Between 500.00 milliamperes source cutoff current and 3.00 amperes source cutoff current **Power Rating Per Characteristic:** 25.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius case **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 case **Specification Data:** 80131-release4482 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:**